MSA-0386

>6V Fixed Gain, 10 dBm General Purpose Amplifier

Description



Lifecycle status: Active



Features

The MSA-03 is a general purpose cascadable 50ohm 10dBm gain block targeted for narrow and wide bandwidth IF amplifier applications. It is offered in a wide variety of plastic and ceramic packages. Bias: 7V, 35mA; f3dB = 2.8GHz; G = 12.5dB; NF = 6dB; P1dB = 10dBm; IP3i = 7.5dBm

MSA-0386

Cascadable Silicon Bipolar MMIC Amplifier



Data Sheet

Description

The MSA-0386 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for use as a general purpose 50Ω gain block. Typical applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using Avago's 10 GHz $\rm f_T$, 25 GHz $\rm f_{MAX}$, silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

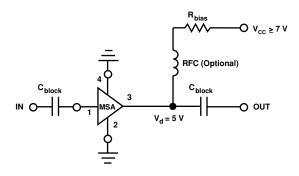
Features

- · Lead-free Option Available
- Cascadable 50Ω Gain Block
- · 3 dB Bandwidth: DC to 2.4 GHz
- 12.0 dB Typical Gain at 1.0 GHz
- 10.0 dBm Typical P_{1 dB} at 1.0 GHz
- Unconditionally Stable (k>1)
- · Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available

86 Plastic Package



Typical Biasing Configuration



MSA-0386 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]	
Device Current	70 mA	
Power Dissipation ^[2,3]	400 mW	
RF Input Power	+13 dBm	
Junction Temperature	150°C	
Storage Temperature	−65 to 150°C	

Thermal Resistance ^[2] :	
$\theta_{\rm jc} = 115^{\circ}{ m C/W}$	

Notes:

- 1. Permanent damage may occur if any of these limits are exceeded.
- 2. $T_{CASE} = 25$ °C.
- 3. Derate at 9.5 mW/°C for $T_{\rm C} > 116 ^{\circ}{\rm C}.$

Electrical Specifications $^{[1]}$, ${\rm T_A}=25^{\circ}{\rm C}$

Symbol	Parameters and Test Conditions: I_d = 35 mA, Z_0 = 50 Ω		Units	Min.	Тур.	Max.
GP	Power Gain $(S_{21} ^2)$	f = 0.1 GHz	dB		12.5	
		f = 1.0 GHz		10.0	12.0	
ΔG_{P}	Gain Flatness	f = 0.1 to 1.6 GHz	dB		±0.7	
f3 dB	3 dB Bandwidth		GHz		2.4	
VSWR	Input VSWR	f = 0.1 to 3.0 GHz			1.5:1	
VSWIL	Output VSWR	f = 0.1 to 3.0 GHz			1.7:1	
NF	$50~\Omega$ Noise Figure	f = 1.0 GHz	dB		6.0	
P _{1 dB}	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm		10.0	
IP3	Third Order Intercept Point	f = 1.0 GHz	dBm		23.0	
$t_{\rm D}$	Group Delay	f = 1.0 GHz	psec		140	
V_{d}	Device Voltage		V	4.0	5.0	6.0
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-8.0	

Note:

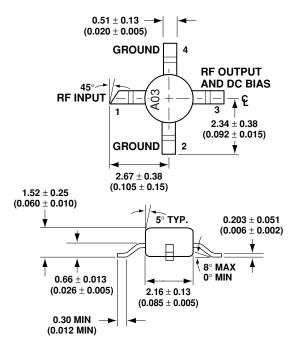
Ordering Information

Part Numbers	No. of Devices	Comments
MSA-0386-BLK	100	Bulk
MSA-0386-BLKG	100	Bulk
MSA-0386-TR1	1000	7" Reel
MSA-0386-TR1G	1000	7" Reel
MSA-0386-TR2	4000	13" Reel
MSA-0386-TR2G	4000	13" Reel

Note: Order part number with a "G" suffix if lead-free option is desired.

^{1.} The recommended operating current range for this device is 20 to 40 mA. Typical performance as a function of current is on the following page.

86 Plastic Package Dimensions



DIMENSIONS ARE IN MILLIMETERS (INCHES)

